

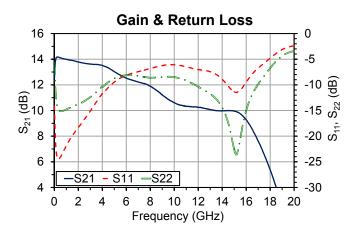
DC-15GHz, 15dBm Wideband General Purpose Amplifier

Features

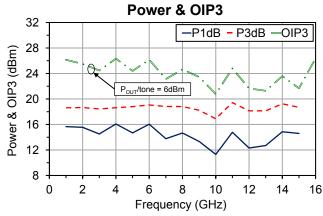
- >18dBm P_{3dB} to 15GHz
- 20-26dBm IP3 to 15GHz
- >10dB gain to 15GHz
- Input and output matched to 50Ω
- 100% DC and RF tested
- 3x3 DFN-6 plastic overmold package

Applications

- Instrumentation
- Electronic warfare
- Microwave communications
- Radar







Typical Performance (CW, Typical Device, Evaluation Board): T_A = 25°C, V_{DD} = 4V

Parameter	DC - 6GHz	Units	
Small Signal Gain	13.5	12	dB
Output Power, P _{1dB}	15.5	14.0	dBm
Output Power P _{3dB}	18	18	dBm
Output IP3	26	29	dBm
I_{DD}	4	mA	



Table 1: Absolute Maximum Ratings, Not Simultaneous

Parameter	Rating	Units
Drain Voltage (V _{DD})	+4.5	V
Input Power (P _{IN})	TBD (6 est)	dBm
Channel Temperature (T _C)	150¹	°C
Operating Ambient Temperature (T _A)	-55 to +85	°C
Storage Temperature	-65 to +150	°C
Thermal Resistance, Channel to Die Backside (R _{TH})	TBD	°C/W

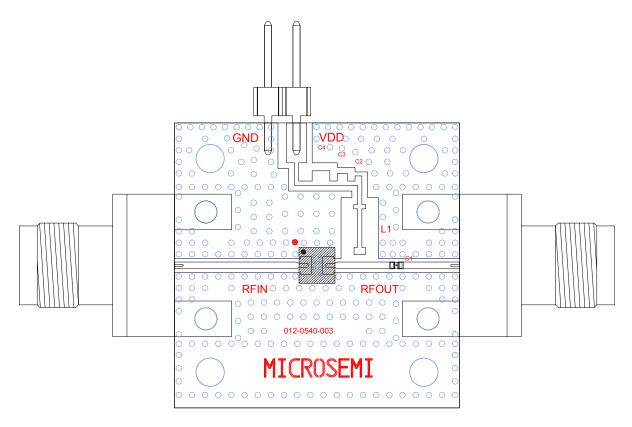


Table 2: Specifications (CW, 100% Test): $T_A = 25$ °C, $V_{DD} = 4V$

Parameter	Frequency	Min	Тур	Max	Units
I _{DD}	-	TBD	45	TBD	mA
Small Signal Gain	15GHz	TBD	TBD	-	dB
Output Power, P _{1dB}	15GHz	TBD	TBD	-	dBm

Evalutation Board

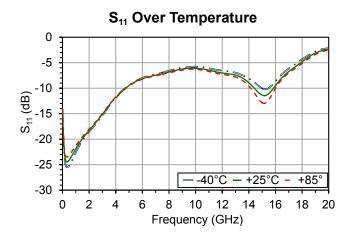
With SMK 2.92mm Connectors

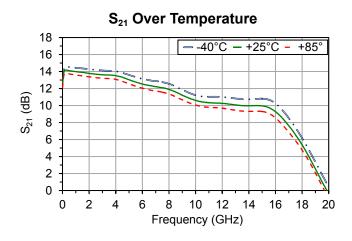


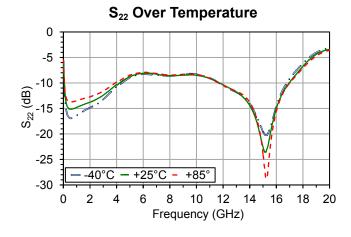
 $^{^{1}}$ MTTF > 10 8 hours at T_C = 150 $^{\circ}$ C

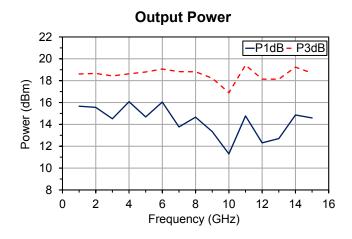


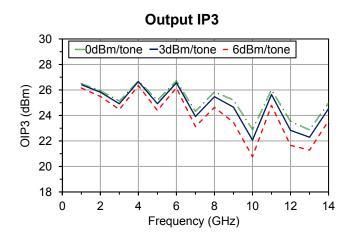
Typical Performance V_{DD} = 4V, I_{DD} = 45mA, T_A = 25°C, in evaluation board, unless otherwise noted





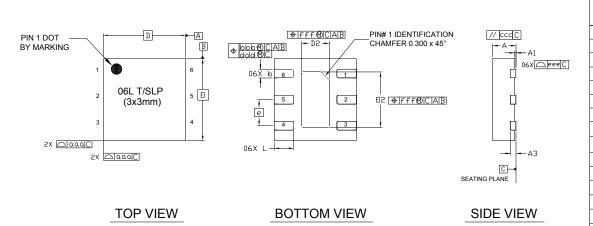








Microsemi QA Package Outline



Dimensional Ref. REF. Min. Nom 0.700 0.750 0.800 0.800 0.850 0.900 A1 0.050 0.000 А3 0.203 REF D 3.000 BSC Ε 3.000 BSC D2 0.970 1.020 1.070 E2 1.970 2.020 2.070 b 0.270 0.320 0.370 е 0.950 BSC L 0.662 0.712 0.762 Dimensional Tol. aaa 0.050 bbb 0.100 CCC 0.050 ddd 0.050 eee 0.080 fff 0.050

NOTE:

DIMENSIONS ARE IN MM

Table 3: Pinout

Pad #	Description	
1,3,4,6	Ground	
2	RF _{IN} , Pad is DC Coupled	
5	RF _{OUT} , Pad is DC Coupled	
Exposed Pad	Ground, thermal path	



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